168/2024

Maximum: 100 marks Time: 1 hour and 30 minutes 1. Unit of specific resistance is: (A) Ω (B) $\Omega - m$ (C) Ω / m (D) Ω / mV The value of temperature co-efficient of resistance depends upon: 2. Nature of the material and temperature (i) Nature of the material and length of the material (ii) (iii) Length of the material and volume of the material (iv) Nature of the material and volume of the material (A) Only (i) and (ii) (B) Only (ii) and (iii) (C) Only (i) (D) Only (iii) 3. In resistor colour coding if the third band is gold, it represents a multiplying factor of: (A) 0.01 (B) 0.1 (C) 0.2(D) 0.54. Combined or equivalent resistance of a parallel circuit is: (A) Less than the least amongst them Higher than the least amongst them (B) (C) Higher than the highest amongst them (D) Less than the highest amongst them

5. Ceramic capacitor has a approximate capacitance range of:

> 3 pF to 30 pF (A)

(B) $2 \mu F \text{ to } 2000 \mu F$

(C) $3 \text{ pF to } 2000 \,\mu\text{F}$

(D) $3 pF to 2 \mu F$

6.	Five equal capacitors connected in series have a resultant of 4 μF . When these connected in parallel and charged to 400 Vdc supply. Then the total energy stored is :			
	(A)	28 J	(B)	38 J
	(C)	18 J	(D)	8 J
7.	when con	each having an inductance of 250 μH nected series aiding and 450 μH who ductance :		•
	(A)	100 μΗ	(B)	50 μΗ
	(C)	$25~\mu H$	(D)	150 μΗ
8.		s a resistance of 30Ω and an inductan Hz supply. Find impedance :	ce of	127.3 mH. It is connected across a
	(A)	10Ω	(B)	50Ω
	(C)	350Ω	(D)	150Ω
9.	A transfor	rmer is an efficient device because it :		
	(A)	It uses inductive coupling		
	(B)	It uses capacitive coupling		
	(C)	It uses electric coupling		
	(D)	Is a static device		
10.	What is the	ne approximate efficiency of large trans	forme	ers?
	(A)	95%	(B)	75%
	(C)	85%	(D)	65%
11.	In Silver	Oxide cell, the anode is made up of :		
	(A)	Silver Oxide		
	(B)	Magnesium Oxide		
	(C)	Zinc in an alkaline electrolyte		
	(D)	Carbon in an alkaline electrolyte		

	(A)	0.45 Vs(rms)	(B)	0.48 Vs(rms)
	(C)	0.54 Vs(rms)	(D)	0.58 Vs(rms)
13.	A dovice v	whose characteristics are very close to t	hat of	an idaal valtaga sayrga is a :
10.				_
	(A)	Transistor	(B)	DIAC
	(C)	FET	(D)	Zener diode
14.	Which of t	the following is a switching voltage reg	ulator	?
	(A)	79S40	(B)	78S50
	(C)	78S40	(D)	79S50
15.	Inverter is	s a device that :		
	(A)	converts fixed dc power into variable	dc pov	ver
	(B)	converts variable dc power into fixed	dc pov	ver
	(C)	converts ac power into dc power		
	(D)	converts dc power into ac power		
16.	The resist	ance of voltmeter is usually		
	(A)	Very low	(B)	Low
	(C)	Medium	(D)	High
17.	Unit of su	sceptibility is		
	(A)	Webbers/meter square	(B)	Henry per meter
	(C)	Tesla	(D)	No units
18.	Range ext	ension of Ammeter requires ————	— wi	th milli ammeter
	(A)	A shunt resistor	(B)	A series resistor
	(C)	Series multiplier	(D)	None of these

12. In half wave rectifier DC output voltage in terms of $V_{\rm S}(\text{rms})$:

19.	. Norton's theorem is ————— form of an equivalent circuit			
	(A)	Voltage	(B)	Current
	(C)	Both (A) and (B)	(D)	None of these
20.	Air frictio	n damping is used in the instrument w	hich i	s
	(A)	Moving iron	(B)	Moving coil
	(C)	Induction	(D)	Hot wire
21.	In an R –	${f L}-{f C}$ circuit, the phase of the current	with r	espect to the circuit voltage will be
	(A)	Leading		
	(B)	Same		
	(C)	Lagging		
	(D)	Depends up on the value of L and C		
22.	Which of	the following are used to increase the r	ange o	of ammeters?
	(A)	Multipliers	(B)	Shunts
	(C)	Control spring	(D)	Potential transformers
23.	The power	r in a pure inductive circuit is		
	(A)	Zero	(B)	Unity
	(C)	Above unity	(D)	None of these
24.	When ac	voltage is connected to a PMMC meter,	then	
	(A)	The meter will get damaged		
	(B)	The reading is zero		
	(C)	Three pointer will oscillate to and fro		
	(D)	The range of the pointer will move at	all	
25.	Value of c	eurrent at resonance in a series RLC ci	rcuit is	s affected by the value of:
	(A)	L (Inductance)	(B)	C (Capacitance)
	(C)	R (Resistance)	(D)	None of these

26. The time base signal in a CRO is:				
	(A)	A sinusoidal signal		
	(B)	A square wave signal		
	(C)	A sawtooth signal		
	(D)	A triangular wave signal		
27.	Ohm's law	v is not applicable to:		
	(A)	DC circuits	(B)	High currents
	(C)	Small resistors	(D)	Semi conductors
28.	The sourc	e of electron beam in a CRO is:		
	(A)	Electron gun	(B)	Grid
	(C)	Focussing anode	(D)	Vertical deflection plates
29.	Which one	e has negative temperature co-efficient o	of resi	istance?
	(A)	Copper	(B)	Carbon
	(C)	Aluminium	(D)	Iron
30.	The intern	nal resistance of an ammeter should be:		
	(A)	Very small	(B)	Medium
	(C)	High	(D)	Infinity
31.	According	to Krichoff's first law current at a junc	tion is	s:
	(A)	Sum of the incoming current		
	(B)	Sum of the voltages		
	(C)	Sum of the outgoing current		
	(D)	Zero		
32.	Dual bean	n oscilloscope has:		
	(A)	Two screens		
	(B)	Two different phosphor coatings		
	(C)	Two electron guns		
	(D)	Single beam with time multiplexing		

	(A)	Duality	(B)	Linearity
	(C)	Reciprocity	(D)	Non-linearity
9.4	The signed	l to be absorbed on the source of on so	: 11	no is smalled form
34.		l to be observed on the screen of an os	scillosco	pe is applied for:
	(A)	Across its vertical plates		
	(B)	Across its horizontal plates		
	(C)	To the horizontal amplifier		
	(D)	To the trigger circuit		
35.	The curre	ent carrying capacity of a copper wi	re havi	ng twice the diameter of another
	(A)	Twice as great	(B)	Half as great
	(C)	Four times as great	(D)	Three times as great
36.	In a CRO	'X' axis normally represents:		
	(A)	Time	(B)	Gain
	(C)	Voltage	(D)	Current
37.	Moving Ir	on instruments have ———— sc	ale.	
	(A)	Squared	(B)	Uniform
	(C)	Log	(D)	None of these
38.	The diode carriers is	e when reverse biased, the current called:	flowing	g through it due to the minority
	(A)	Forward current	(B)	Saturation current
	(C)	Eddy current	(D)	None of these
39.		le multivibrator using IC 555 has Then what will be the frequency of or		
	(A)	10 kHz	(B)	100 Hz
	(C)	1 Hz	(D)	100 kHz
168/	/202 <i>4</i>	8		A

The "Superposition theorem" is essentially based on the concept of :

33.

40. The GBP of an OP-AMP is specified as 1 MHz What is the maximum gai obtained using this Op-Amp at 1 kHz:			is the maximum gain that can be	
	(A)	10	(B)	100
	(C)	1000	(D)	10000
41.		r test with ohm meter base to collecte tion show low resistance so transistor		emitter in forward bias and reverse
	(A)	Good	(B)	Open
	(C)	Short	(D)	None of these
42.	What is th	ne output resistance of common collec	tor conf	figuration of amplifier?
	(A)	Less than 100 Ω	(B)	More than $1000~\Omega$
	(C)	More than $10~\mathrm{K}\Omega$	(D)	Less than 1 Ω
43.	Current g	ain of a common emitter amplifier is	:	
	(A)	Ic/Ie	(B)	Ib/Ic
	(C)	Ie/Ic	(D)	Ic/Ib
44.	In crystal	oscillator the crystal also convert ele	ctrical e	energy into ———— energy.
	(A)	Light energy	(B)	Magnetic energy
	(C)	Mechanical energy	(D)	Heat energy
45.	Which tra	nsistor amplifier has an efficiency of	about 8	5%?
	(A)	Class-A	(B)	Class-B
	(C)	Class-C	(D)	Class-AB
46.	According	to barkhausen, loop gain is :		
	(A)	$A\beta = 1$	(B)	$A\beta \le 1$
	(C)	$A\beta > 1$	(D)	None of these

168	/2024			10	A	4
		(C)	5 W	(D)	4 W	
		(A)	6 mW	(B)	600 mW	
52.	The	maxii	mum power of a 555 IC ca	ın dissipate is arouı	nd:	
		(C)	Quarter cycle	(D)	Three quarters of cycle	
		(A)	Half cycle	(B)	Full cycle	
51.	Class	•	peration of amplifier, one			
		(C)	Output	(D)	Offset null	
		(A)	+ VCC	(B)	-VCC	
50.	Pin l	No 1 c	of IC LM 741 is:			
		(C)	Only (iii)	(D)	Only (i), (ii) and (iii)	
		(A)	Only (i)	(B)	Only (i) and (ii)	
	(iii)	Radi	io Receivers			
	(ii)	Digi	tal Computers			
	(i)	Rada	ars			
49.	Clip	per ci	rcuit has grate application	n in :		
		(C)	Only (ii) and (iii)	(D)	Only (iii)	
		(A)	Only (i)	(B)	Only (i) and (ii)	
	(iii)	Rela	xation oscillators			
	(ii)	Non	sinusoidal oscillators			
	(i)	Sinu	isoidal oscillators			
48.		outpi vn as		be square, triangu	lar or saw tooth wave form, it i	s
		(0)	j = 1/2 π HC	(D)	7 - 17 2 11 EC	
		(A) (C)	$f = 2\pi / \sqrt{LC}$ $f = 1/2 \pi RC$	(D)	$f = 1/2\pi\sqrt{LC}$ $f = 1/2\pi LC$	
		(A)	$f = 2\pi I / IC$	(B)	$f = 1/9 \pi \cdot /IC$	

 ${f 47.}$ The frequency of oscillations in Wein bridge oscillator is :

A		11		168/2024 [P.T.O.]		
	(D)	the voltage at drain terminal contr	cols the m	nain current		
	(C)	the voltage at source terminal conf	trols the i	main current		
	(B)	the current through the gate contr	ols the m	ain current		
	(A)	the voltage at the gate controls the	e main cu	rrent		
58.	In JFET,					
	(C)	Germanium oxide	(D)	Germanium dioxide		
	(A)	Silicon monoxide	(B)	Silicon dioxide		
57 .	The insula	ating layer of MOSFET is:				
	(C)	0.4 to 1	(D)	0.5 to 0.8		
	(A)	0.4 to 0.9	(B)	0.5 to 0.9		
56.	Typical va	alue of intrinsic stand off ratio of UJ	T vary fr	om:		
	(C)	Saturation current	(D)	None of the above		
	(A)	Valley current	(B)	Peak point current		
55.	Minimum known as	amount of emitter current to place:	e the UJ	T in negative resistance region is		
			, ,			
	(C)	Gate voltage	(D)	Gate current		
	(A)	Emitter current	(B)	Collector current		
54.	An IGBT	is driven by :				
	(D)	Low input impedance and small bi	polar cur	rent carrying capability		
	(C) High input impedance and small bipolar current carrying capability					
	(B)	Low input impedance and large bipolar current carrying capability				
	(A)	High input impedance and large bipolar current carrying capability				

53. IGBT has:

	(B)	gate is either forward or reverse biased		
	(C)	gate always reverse biased		
	(D)	bias voltage is not required at gate ter	minal	I
60.		num drain current (Id) of BFW 10 JFE	l' is,	
	(A)	25 mA	(B)	10 mA
	(C)	100 mA	(D)	20 mA
61.	The curren	nt through the SCR can be turned off:		
	(A)	only by reducing the load current below	w the	holding current
	(B)	only by removing the gate current		
	(C)	by reducing the forward break over vo	ltage	
	(D)	by reducing the forward blocking volta	ıge	
62.	The termi	nals of TRIAC,		
	(A)	Anode, Cathode, Gate		
	(B)	Emitter, Base1, Base2		
	(C)	Main terminal 1, Main terminal 2, Ga	te	
	(D)	Gate, Emitter, Collector		
63.	Which of t	the following is a TRIAC?		
	(A)	2N 2646	(B)	BT 136
	(C)	DB 3	(D)	TYN 640
64.	The DIAC	acts in a similar manner to,		
	(A)	two transistors connected in series		
	(B)	two SCRs connected in antiparallel		
	(C)	one diode and two resistors		
	(D)	two diodes connected in reverse parall	el	
1.00	1000 A	10		

59. For the biasing of JFET,

(A) gate always forward biased

	(A)	Ripple factor	(B)	Cut off factor
	(C)	Fusing factor	(D)	Form factor
66.	Which typ	pe of MCB is designed to pr	rotect circuits with	inductive load?
	(A)	L series MCB		
	(B)	G series MCB		
	(C)	DC series MCB		
	(D)	Both L series and DC ser	ries MCB	
67.	What is tl	he full form of abbreviation	n ELCB used in ele	ctrical circuits?
	(A)	Electrical Live Contact B	breaker	
	(B)	Equipment Load Circuit	Breaker	
	(C)	Earth Leakage Circuit B	reaker	
	(D)	Earth Load Circuit Breal	ker	
68.	A device v	=	uxiliary circuit und	der predetermined condition in the
	(A)	Resistor	(B)	Capacitor
	(C)	Fuse	(D)	Relay
69.		pe of DC motor has 2 field ther is connected parallel v		ected in series with the armature
	(A)	Series motor	(B)	Shunt motor
	(C)	Compound motor	(D)	Induction motor
70.	For 100% is 6000 W		the power transmi	tted by carrier signal if total powe
	(A)	1000 W	(B)	2000 W
	(C)	4000 W	(D)	6000 W

 $\textbf{65.} \quad \text{Ratio between minimum fusing current and current rating is termed as:} \\$

	(A)	$3-30~\mathrm{Hz}$	(B)	$3-30~\mathrm{kHz}$
	(C)	$3-30~\mathrm{MHz}$	(D)	30 MHz - 3 GHz
72.	An Omnio	lirectional antenna is designed	to provide —	——— radiation pattern.
	(A)	0°	(B)	90°
	(C)	180°	(D)	360°
7 3.	Which of	the following characteristics ch	anges in Freq	uency Modulation?
	(A)	Carrier Wave frequency		
	(B)	Modulating Wave frequency		
	(C)	Carrier Wave Amplitude		
	(D)	Modulating Wave Amplitude		
74.	According	to Nyquist criteria of sampling	g theorem the	sampling frequency is:
	(A)	Same as the signal frequency		
	(B)	Twice the signal frequency		
	(C)	4 times of signal frequency		
	(D)	5 times of signal frequency		
75.	Which am	ong the following is a digital m	odulation tecl	hnique?
	(A)	AM	(B)	FM
	(C)	Both AM and FM	(D)	ASK
76.		the following device interconn itive optical interface?	ects two separ	rate electrical circuits by means of
	(A)	LED	(B)	LASER
	(C)	Optocoupler	(D)	LDR
77.	The geogr		cation with a s	single transmitter and a receiver is
	(A)	Cell	(B)	Cluster
	(C)	Module	(D)	Cell site
168	/2024		14	\mathbf{A}

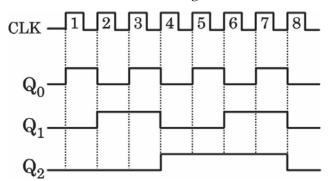
 $\textbf{71.} \quad \text{In Radio frequency spectrum Very Low Frequency (VLF) ranges from}:$

	(A)	SIM	(B)	Barcode
	(C)	Bluetooth	(D)	Multiplexer
79.	The core of	of Optical fiber is made of :		
	(A)	Silica or Glass	(B)	Copper or Aluminium
	(C)	Copper or Silver	(D)	Tungsten
80.	The proce	ss of joining two ends of opt	ical fiber using el	ectric or mechanic means is :
	(A)	Soldering	(B)	Splicing
	(C)	Crimping	(D)	Spacing
81.	Which am	ong the following is not an a	advantage of Geo	synchronous satellite?
	(A)	No need to switch from one	e satellite to othe	r
	(B)	No coverage in polar region	n	
	(C)	Remain stationary relative	e to earth station	
	(D)	The effect of Doppler shift	are negligible	
82.	The comb	-	ier and Transmi	tter in Satellite communication is
	(A)	Transducer	(B)	Multiplexer
	(C)	Sensor	(D)	Transponder
83.	If the nur		ber system is eq	uivalent to 15 in decimal, what is
	(A)	3	(B)	4
	(C)	5	(D)	6
84.	Which of	the following statements is o	correct?	
	(A)	Decimal 10 is represented	as 1000 in binary	z code
	(B)	Decimal 9 is represented a	s 1011 in Excess-	3 code
	(C)	Decimal 9 is represented a	s 1010 in BCD co	de
	(D)	Decimal 10 is represented	as 1111 in Gray o	code
A			15	168/2024

78. Which wireless technology link is used for mobile phone data transfer?

85.	The simplified form of the logic expression $AB + \overline{A}B + A\overline{B} + \overline{A}\overline{B}$:						
	(A)	1	(B)	A			
	(C)	AB	(D)	0			
86.	An OR gate with 2 inputs is followed by a NOR gate, where one input of the NOR gate is grounded. If inputs to the OR gate are $A=1$ and $B=0$, what will be the final output of the circuit?						
	(A)	0					
	(B)	1					
	(C)	Always 0 , regardless of A and B					
	(D)	Always 1, regardless of A and B					
87.	How many select inputs are required for 1:32 demultiplexer?						
	(A)	3	(B)	4			
	(C)	5	(D)	6			
88.	How many	How many 2-to-4-line decoders are required to implement a 4-to-16-line decoder?					
	(A)	2	(B)	3			
	(C)	4	(D)	5			
89.	A 2 input XOR gate can be implemented using a 2:1 multiplexer by :						
	(A)	Connecting one input to the select line, and the other to both data inputs					
	(B)	Connecting one input to the select line, the second input to one data input and the complement of the second input to the other data input					
	(C)	Connecting both inputs to the select line, leaving the data inputs unconnected					
	(D)	Connecting one input to select line and the other input to data input, while grounding the second data input					
90.	_	n a D flipflop, the complement of output is fed back to input. If the clock frequency is 0 Hz, what will be the frequency of the output?					
	(A)	30 Hz	(B)	60 Hz			
	(C)	15 Hz	(D)	10 Hz			

91. The waveforms of a counter are show in the figure below. This is a:



(A) Ring counter

(B) 3-bit ripple counter

(C) Johnson counter

(D) 4-bit ripple counter

92. In a 4-bit ripple counter, if the time period of the input clock pulse is $16 \mu s$, what is the time period of output wave at the most significant bit?

(A) 32 μs

(B) 64 μs

(C) 128 μs

(D) 256 µs

93. What is the ROM address space for an 8051 with 8 KB of on chip ROM?

(A) 0000H to 1FFFH

(B) 0000H to 2FFFH

(C) 0000H to 7FFFH

(D) 0000H to 0FFFH

94. What is the behaviour of the reset pin in the 8051 microcontroller?

- (A) The reset pin is active low and requires a low pulse to be activated
- (B) The reset pin is active high and requires a low pulse to be activated
- (C) The reset pin is active high and requires a high pulse to be activated
- (D) The reset pin is active low and requires a high pulse to be activated

95. Match the following addressing modes with their corresponding 8051 Instructions

- (1) Register
- (i) MOV R5, #25H

(2) Direct

- (ii) ADD A, R7
- (3) Immediate
- (iii) MOV A, @ R0
- (4) Register Indirect
- (iv) MOV R0, 40H

Select the correct match from the options given below

- (A) (1)-(iii), (2)-(iv), (3)-(i), (4)-(ii)
- (B) (1)-(iii), (2)-(i), (3)-(iv), (4)-(ii)
- (C) (1)-(ii), (2)-(i), (3)-(iv), (4)-(iii)
- (D) (1)-(ii), (2)-(iv), (3)-(i), (4)-(iii)

96.	Which of the following is an example of a passive transducer?								
	(A)	Photovoltaic cells	(B)	Thermocouple					
	(C)	Piezoelectric transducer	(D)	Strain gauge					
97.		naracteristic of a thermistor ma are control systems?	kes it	extremely suitable	e for precision				
	(A)	Low thermal conductivity							
	(B)	High resistance variation with temperature							
	(C)	Low specific heat							
	(D)	Linear-temperature-resistance relationship							
98.	Which of	the following is not an advantage of	LVDT?						
	(A)	Linearity	(B)	High hysteresis					
	(C)	Ruggedness	(D)	High sensitivity					
99.	In an inductive transducer, increasing the reluctance of the core will								
	(A)	Decrease the inductance							
	(B)	Increase the inductance							
	(C)	Stabilize the inductance							
	(D)	Not affect the inductance							
100.	The current flow that occurs when two dissimilar conductors are joined to form a thermocouple is primarily due to which effect?								
	(A)	Thomson effect	(B)	See beck effect					
	(C)	Peltier effect	(D)	Hall effect					

SPACE FOR ROUGH WORK

SPACE FOR ROUGH WORK